

Some varieties of amorphous silicon (a-Si) are amorphous silicon carbide (a-SiC), amorphous germanium silicon (a-SiGe), microcrystalline silicon (m-Si), and amorphous silicon nitride (a-SiN). Hydrogen is required to dope the material, leading to hydrogenated amorphous silicon (a-Si:H). The gas phase deposition technique is typically used to form a-Si photovoltaic cells with ...

Silicon-Germanium Alloys for Photovoltaic Applications provides a comprehensive look at the use of Silicon-Germanium alloys Si1-xGex in photovoltaics. Different methods of Si1-xGex ...

Explore the fascinating world of semiconductive materials, such as silicon and germanium, that power our digital age. Semiconductive Materials: An Overview. Semiconductive materials, such as silicon and germanium, play a vital role in the world of electronics and modern technology. These materials, distinct from their conductive and ...

Alloy systems comprised of silicon with germanium, lead with tellurium, and bismuth with antimony have constituted a majority of thermoelectric applications during the last half-century. These legacy materials are primarily covalently bonded with a maximum ZT near one. Silicon-germanium alloys have provided the thermal to electrical conversion for many of ...

Silicon (Si) and germanium (Ge) are semiconducting materials, which are industrially used for the large-scale production of various electronic devices. Solar cells are commonly manufactured from Si. For thermophotovoltaics (TPV) Si has the disadvantage of a high bandgap of 1.1 eV, which requires the use of a spectrally matched selective emitter.

A copper-germanium alloy (Cu-Ge alloy) was examined as a phase change material, at temperatures exceeding 600°C, for latent heat storage in solar thermal applications. First, the thermo-physical properties of the Cu-Ge alloy were examined using differential scanning calorimetry, thermomechanical analysis, and laser flash analysis. Second, to evaluate the ...

Silicon-germanium (Si 1-x Ge x) alloys have been researched since the late 1950s [], but it is only in the past 30 years or so that these layers have been applied to new types of transistor technology.Si 1-x Ge x was first applied in bipolar technologies [22.2, 22.3], but more recently has been applied to metal-oxide-semiconductor (MOS) technologies [22.4, 22.5, 22.6, ...

candidate materials of a phase change material container vessel [stainless steel (SUS310S), Inconel625, silicon carbide (SiC), and alumina (Al2O3)]. The Cu-Ge alloy exhibited significant potential as a latent heat storage material in next-generation solar thermal power plants because it demonstrates various advantages, including a superior



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1 Introduction. III-V solar cells have the highest conversion efficiency of any solar technology, with demonstrated single-junction efficiencies >29%. [] However, high production costs keep III-Vs from widespread use in terrestrial applications. [] The cost of epitaxial growth, the single-crystal substrate on which solar cells are grown, and back-end ...

Table 1 compares SiGe to silicon, germanium, and other semiconductor materials in terms of performance, power consumption, and comparisons for certain applications. Table 1. Comparison of SiGe with Silicon, Germanium, ...

Silicon Diode Germanium Diode; Material: Silicon (Si) Germanium (Ge) Bandgap Energy: 1.12 eV: 0.67 eV: Forward Voltage Drop ~0.7 V ~0.3 V: Leakage Current: Low: High: Thermal Stability: High (up to 200°C) Limited (up to 85°C) Sensitivity to Temperature: Low: High: Power Handling Capability: High: Moderate: Cost: Generally lower: Generally ...

In contrast, the Si/Ge superlattice solar cell is superior with the ability not only to absorb 90% of photons energy at near IR range but also across the

In this paper, we will present ab-initio results of the structural, electronic and optical properties of (1) silicon and germanium nanoparticles embedded in wide band gap materials and (2) ...

Solar cells can be categorized according to their material composition whereas silicon-based semiconductors are dominant in the industrial share of photovoltaics, and despite considering the advantages of silicon material in photovoltaics, they lack some factors, such as very low absorbing power as well as needing almost 200-300 semiconducting material films ...

traditional fixed solar system and the concentrated germanium solar power generation sunny system are compared and analyzed by SIMULINK modeling, and the results show that the so-

In this work, p-i-n hydrogenated amorphous silicon germanium (a-SiGe:H) thin film solar cells were fabricated by using double p-type silicon oxide (p-SiOx) layers, and the power conversion ...

Silicon-germanium is an important material that is used for the fabrication of SiGe heterojunction bipolar transistors and strained Si metal-oxide-semiconductor (MOS) transistors for advanced complementary metal-oxide-semiconductor (CMOS) and BiCMOS (bipolar CMOS) technologies. It also has interesting optical properties that are increasingly being applied in ...

Thermoelectric power sources have consistently demonstrated their extraordinary reliability and longevity for



deep space missions (67 missions to date, more than 30 years of life) as well as terrestrial applications where unattended operation in remote locations is required. The development of new, more efficient materials and devices is the key to ...

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A team of researchers from MIT and the Masdar Institute of Science and Technology has developed a new solar cell that combines two different layers of sunlight-absorbing material to harvest a broader range of ...

The demand for elemental germanium and its compounds is increasing and is expected to increase in the near future [6], [7]. The main sources of germanium are zinc refinery residues and fly ash, and thus its production increase depends on the motivation of zinc refineries and coal power plants to engage in the germanium market [8]. As such, worldwide, only 3-5% ...

germanium quantum dot solar cell made with a gas aggregation nanoparticle source is presented. UV-vis spectroscopy reveals quantum confinement, and the spectral response of the germanium quantum dot Grätzel-type solar cell confirms the presence of large and small band gap optical absorption due to a mix of particle sizes. Some of the particles are small enough to ...

We designed three generation Ge:Si solar cells and predicated their performance below Si. We achieved Ge:Si solar cells on low cost Si substrates by RPCVD ...

Nuclear fusion reaction on the sun is the largest source of energy. In this paper, qualitative investigation of the numerical model of silicon germanium heterojunction solar cell is performed ...

Multijunction solar cells designed from silicon (Si)-germanium (Ge) alloy based semiconductor materials exhibit high theoretical efficiencies (19.6%) compared to the single junction one. The modeling calculations for all solar cells are done by AMPS 1D simulator. The structure of multi-junction i-layer is designed using heterolayers, starting ...

5. Construction Thermoelectric power generation (TEG) devices typically use special semiconductor materials, which are optimized for the Seebeck effect. The simplest TEG device consists of a thermocouple, comprising a p- type and n-type material connected electrically in series and thermally in parallel. Heat is applied into one side of the couple and ...

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Contrasting silicon-based brethren, germanium solar cells showcase reduced recombination frequencies courtesy of superior conductive traits. Recombination delineates a process where electrons forfeit their energy ...

Recent developments in the use of nano-materials for solar power generation, including silicon and gallium arsenide nanowires, are also reviewed. View. Show abstract. Thin-Film Silicon Solar Cells ...

Exposed in step-like formation, layers of new photovoltaic cell harvest more of sun's energy. A silicon solar cell with silicon-germanium filter using a step-cell design (large) and a gallium arsenide phosphide layer on ...

River lines are more problematic for device performance, resulting in consistently lower-performing solar cells associated with a high dislocation density in the cell material. We demonstrate a 23.4% efficient ...

Keywords: phase change material, thermal storage system, latent heat, copper-germanium alloy, concentrated solar power. Citation: Gokon N, Jie CS, Nakano Y, Okazaki S, Kodama T, Hatamachi T and Bellan S (2021) ...

Later, Meyerson discovered that when silicon was cleansed in hydrofluoric acid, a protective hydrogen layer would form, negating the need to heat silicon to 1000°C to rid silicon of the contaminating oxide. At 600°C, the ...

materials and material alloys and their thermal and electric transport parameters are inverstigated (6-8). As of yet, none of these is suitable for a broad economical use. To increase the conversion efficiency, we present a new approach to thermoelectric power generation using large area SiGe pn-junctions (9).

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